

On the performance of multilayers used as monochromators for coherent X-ray imaging with hard synchrotron radiation

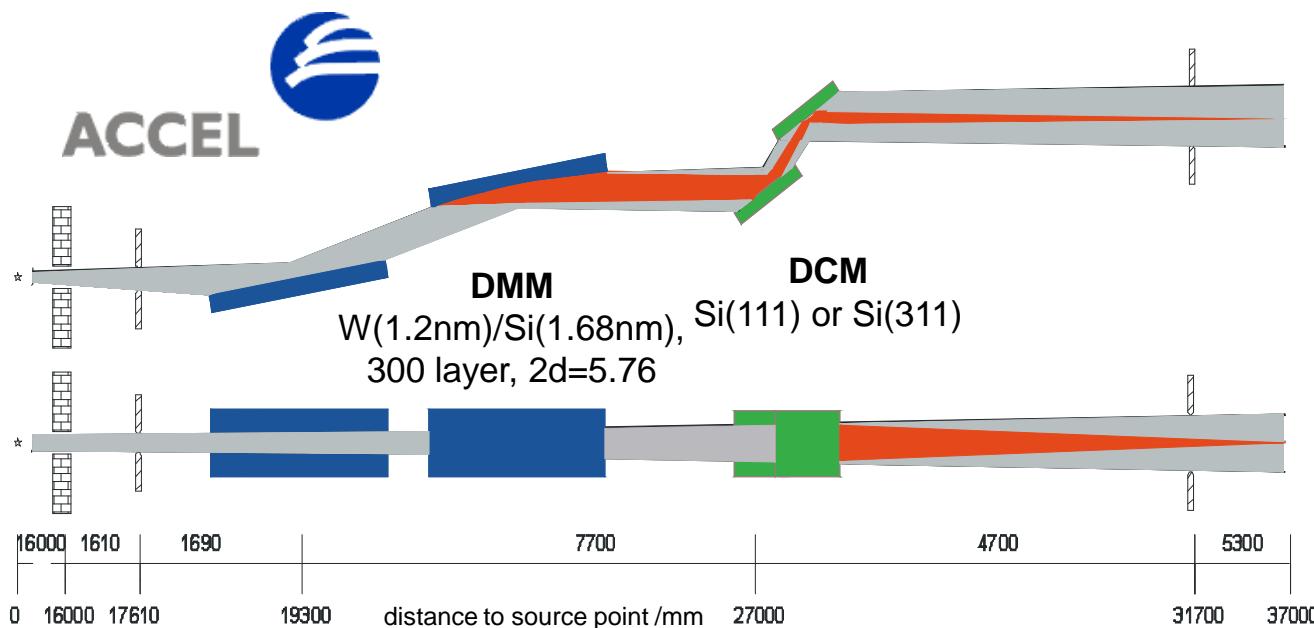
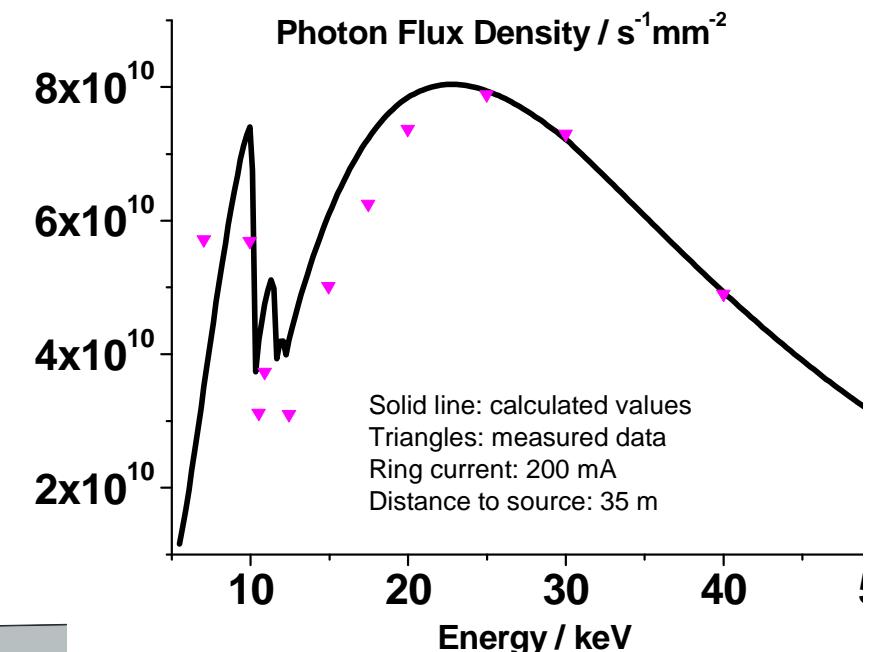
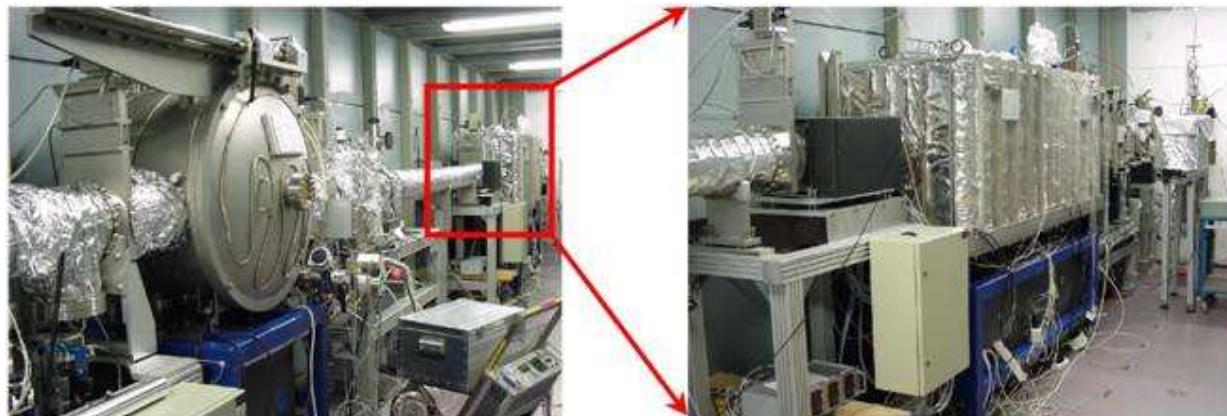
online version

**A. Rack, T. Weitkamp, R. Dietsch, M. Riotte, T. Rack,
T. Holz, M. Krämer, F. Siewert, Ch. Morawe, I. Zanette,
A. Cecilia, P. Vagovič, M. Meduňa, P. Cloetens, E. Ziegler**



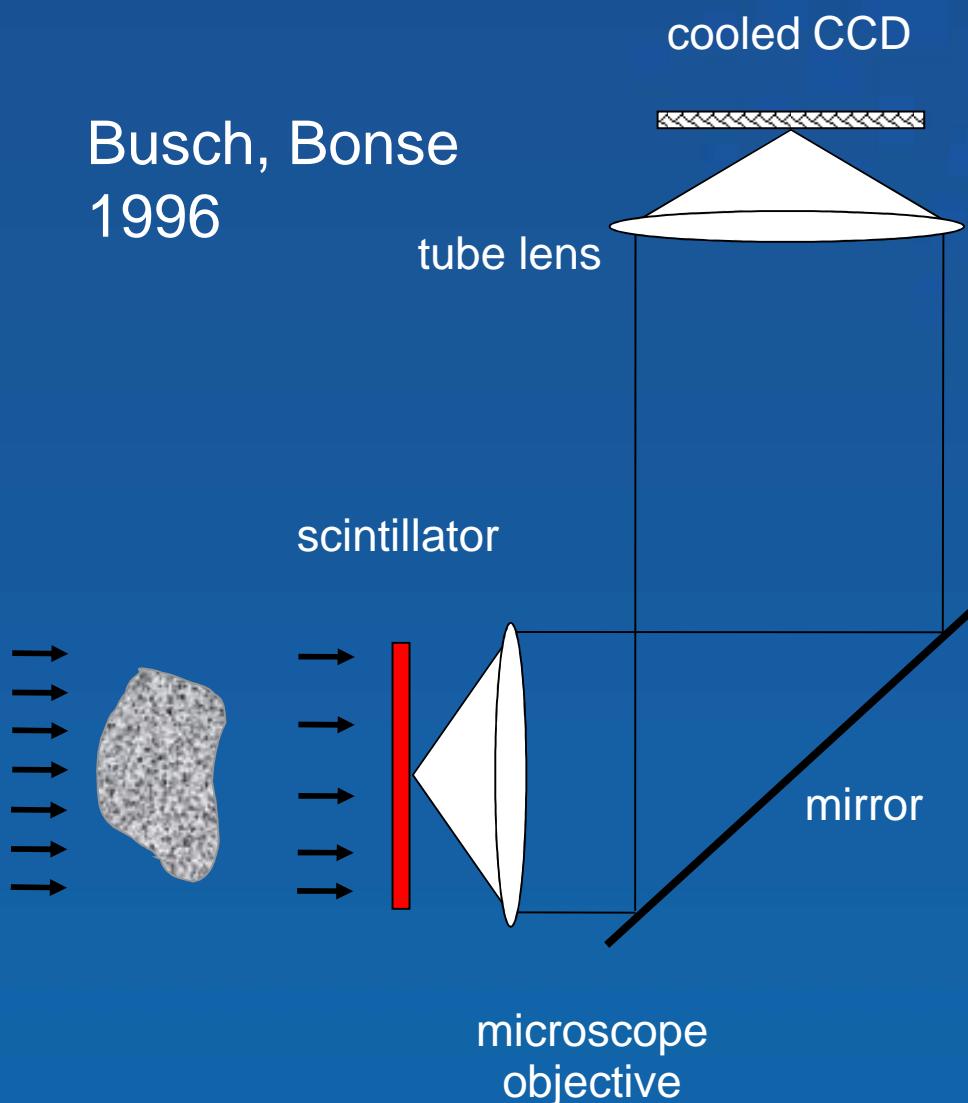
European Synchrotron Radiation Facility

Synchrotron micro-imaging using hard X-rays



- BESSY - 1.7 GeV, 330 m, 3rd generation source
- BAMline - 7T WLS insertion device
- Görner et al, NIMA 2001
- Rack et al, NIMA 2008

Busch, Bonse
1996

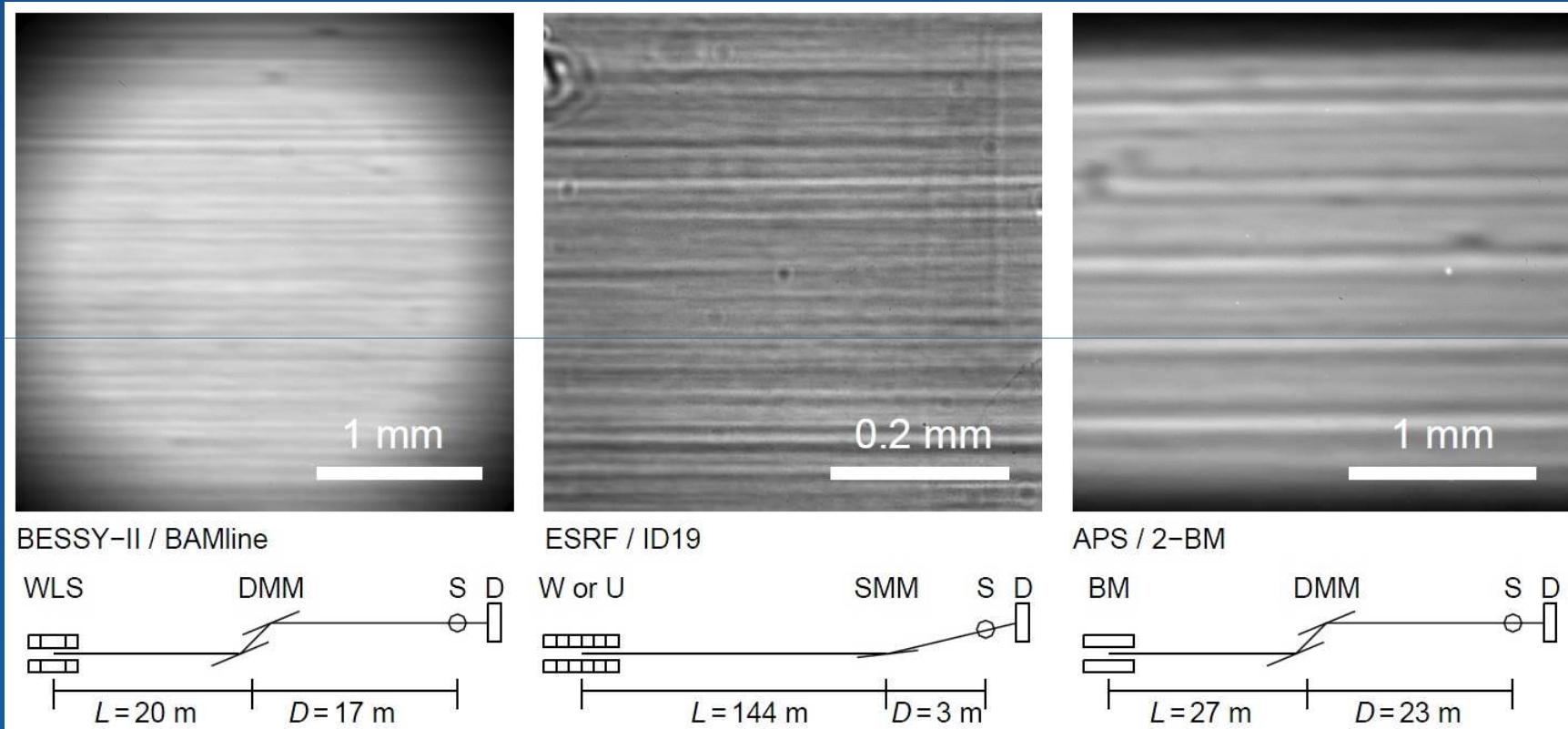


FReLoN CCD (ESRF) mounted on Optique Peter microscope (ANKA - TopoTomo-BL)



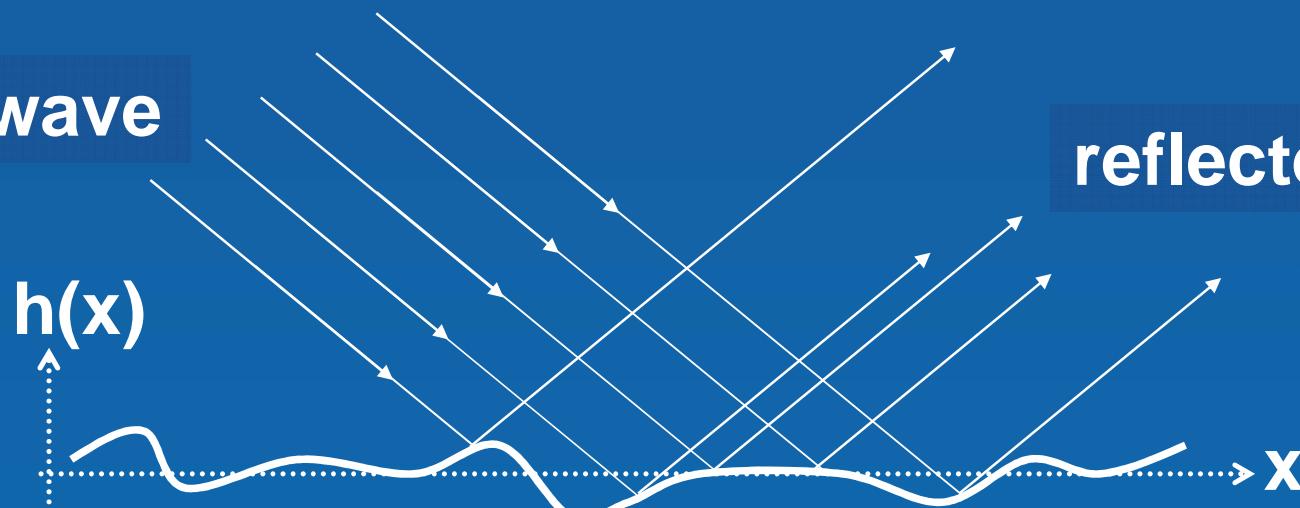
- mouthpart kinematics during feeding
- 125 FPS
- 15 μm spatial detector resolution
- Rack et al., J X-ray Sci Techn `10
- Westneat, Betz et al., Science `03

CMOS camera, macroscope, white bending magnet beam

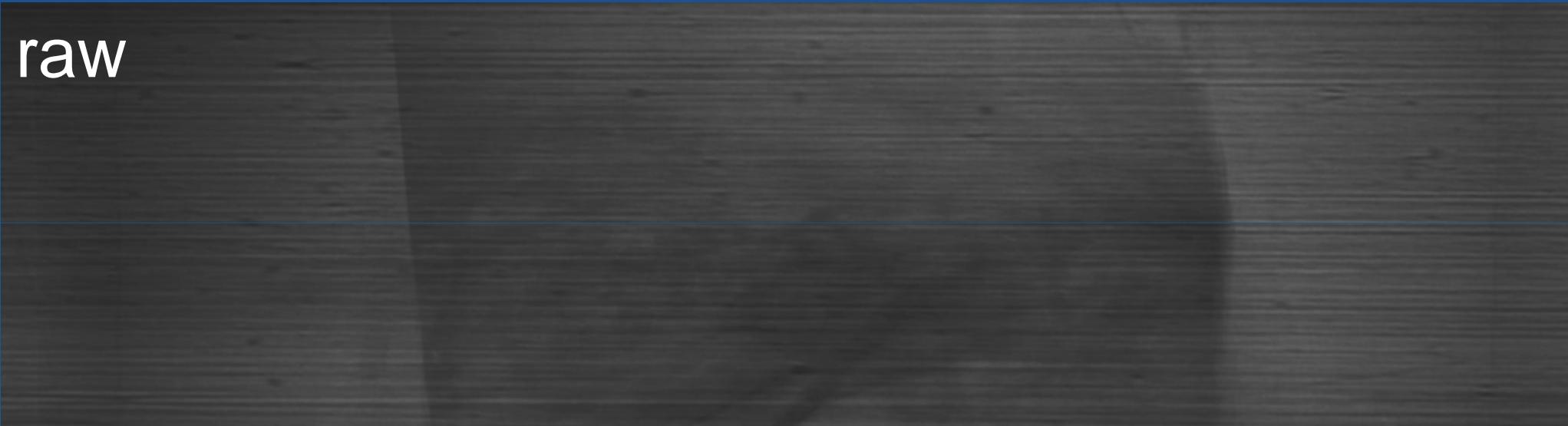


incident wave

reflected wave

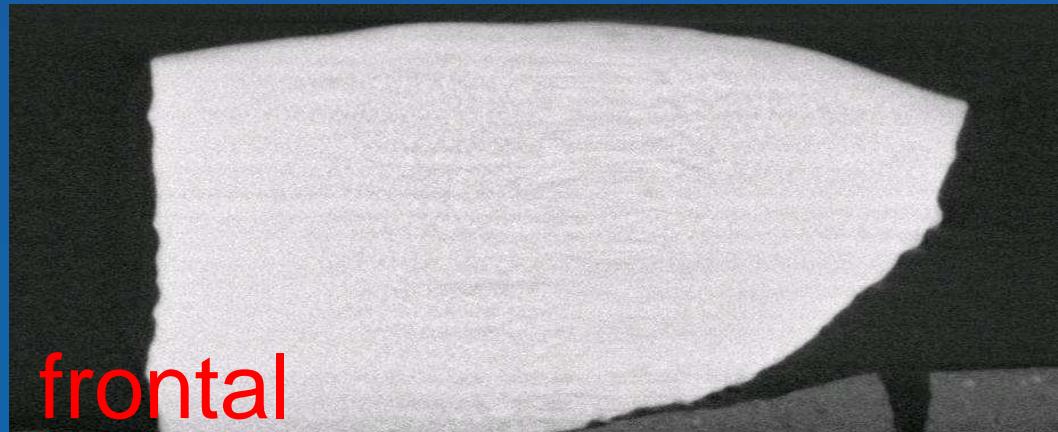
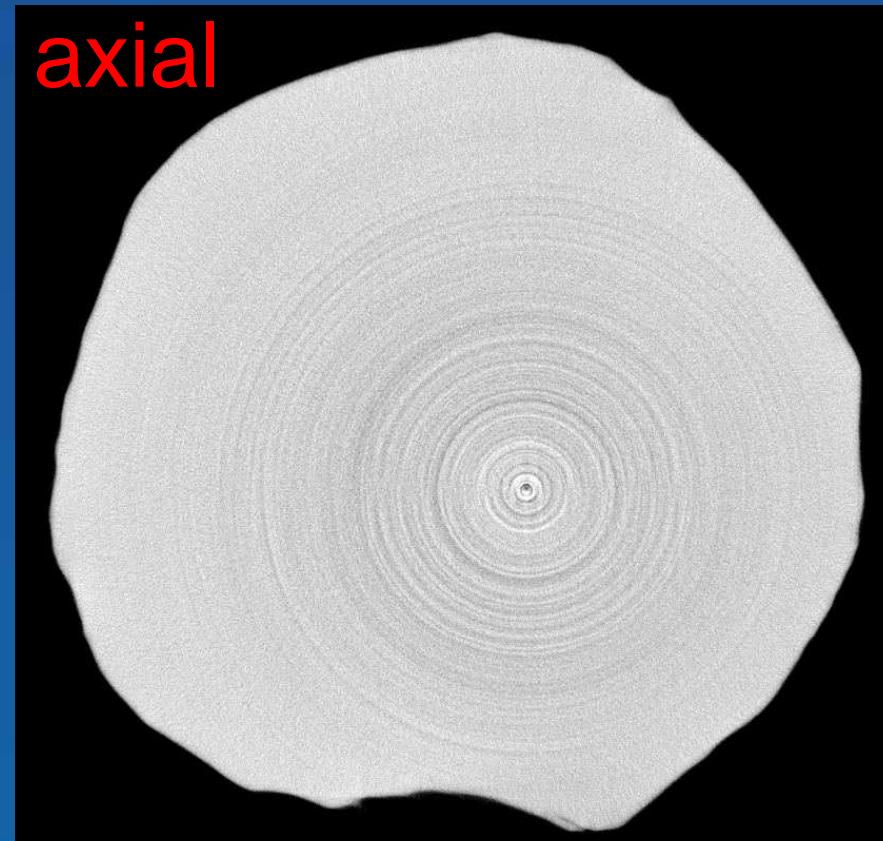


raw



corrected





Multilayers & Methods

Si substrates (25.4 mm diameter, 6.35 mm thick), one-sided superpolished - General Optics, Gooch & Housego

Serial number	Materials	N	d (nm)	R_8^{exp}	R_8^{calc}	R_{18}^{calc}
1531	W/Si	120	2.528	-†	76%	78%
1574	Mo/Si	220	2.478	>45% †	77%	93%
1601	Mo/Si	80	3.975	70%	77%	93%
1609	Mo/Si	50	5.492	75%	76%	93%
1680	Pd/B ₄ C	220	2.468	>50% †	76%	93%
1681	Pd/B ₄ C	60	4.002	70%	76%	93%
1685	Pd/B ₄ C	30	3.982	61%	70%	86%

$$\Gamma = 0.5 \text{ (nominal)}$$

High Precision Large Area Deposition of Nanometer Multilayers

Combination of complementary
high precision deposition
technologies

- Magnetron Sputtering (MSD)
- Large-Area PLD (LA-PLD)
- Dual Ion Beam Sputter
Deposition (DIBD)*

MSD and DIBD (UHV conditions):

- 8" diameter substrates
- 500 mm substrate length



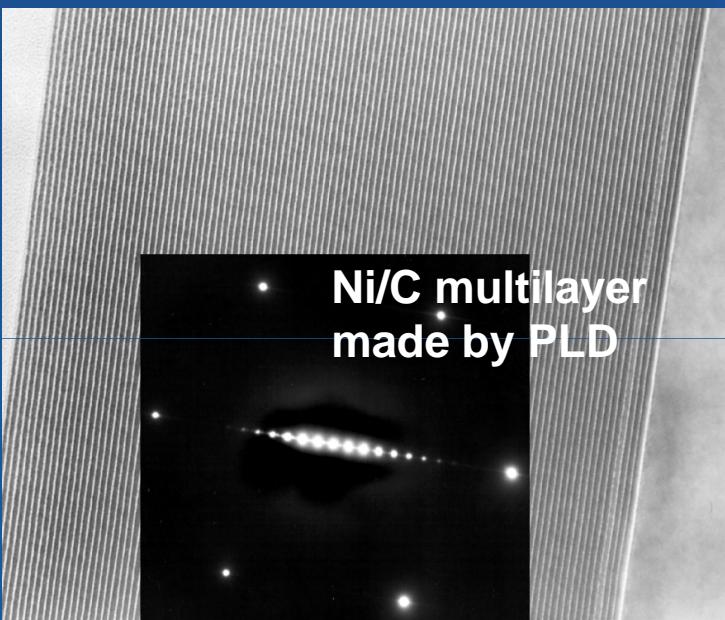
LA-PLD / MSD: UHV cluster-tool system*

- 6" diameter substrates
- automated deposition of nm-ML

* in cooperation with
Fraunhofer IWS



AXO Dresden GmbH
Applied X-ray Optics
High Precision Deposition



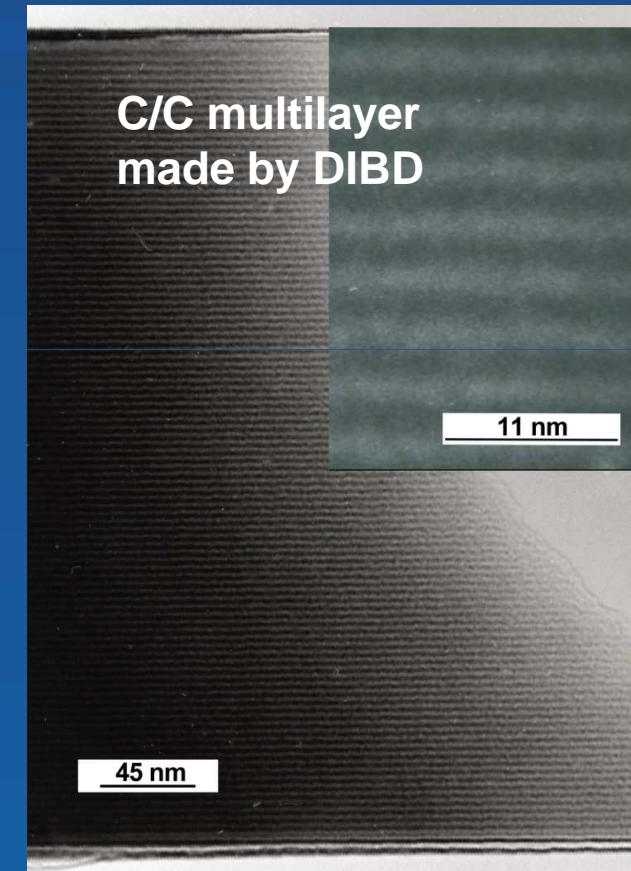
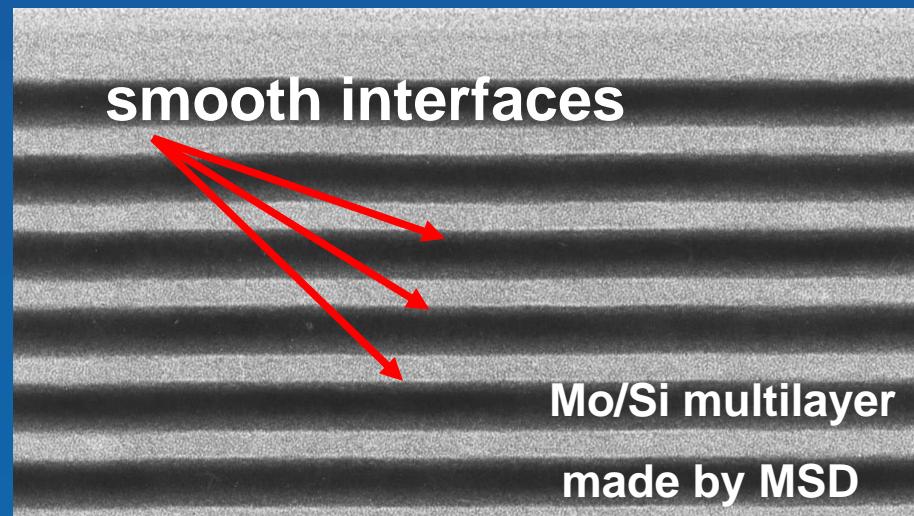
Ni/C multilayer
made by PLD

MSD: W/Si,
Mo/Si ($R_{13.4\text{nm}} = 70.1\%$)

DIBD: Ni/B₄C,
C/C, a-C

PLD: Ni/C,
C/C, a-C

HRTEM of a PLD-Ni/C multilayer (100 layer pairs, d = 3.2 nm) and reciprocal space image of electron diffraction



11 nm

45 nm



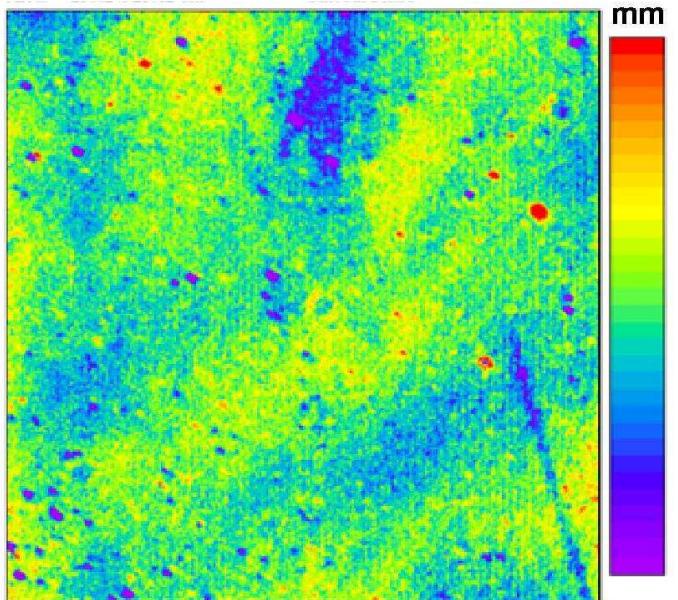
- BESSY-NOM
- Interference microscope
- AFM
- substrates (1", GO)
before and after coating

Siewert et al., NIMA 616 (2010)

- Specular and non-specular X-ray reflectivity
(SCD beamline, ANKA and Cu- k_α laboratory source, AXO Dresden GmbH)
 - *interlayer and surface roughness*
- Full-field X-ray imaging (TopoTomo beamline, ANKA and beamline BM05, ESRF)
 - *stripe modulations and spatial resolution*
- (Fractional) Talbot imaging (beamline ID19, ESRF)
 - *coherence preservation*

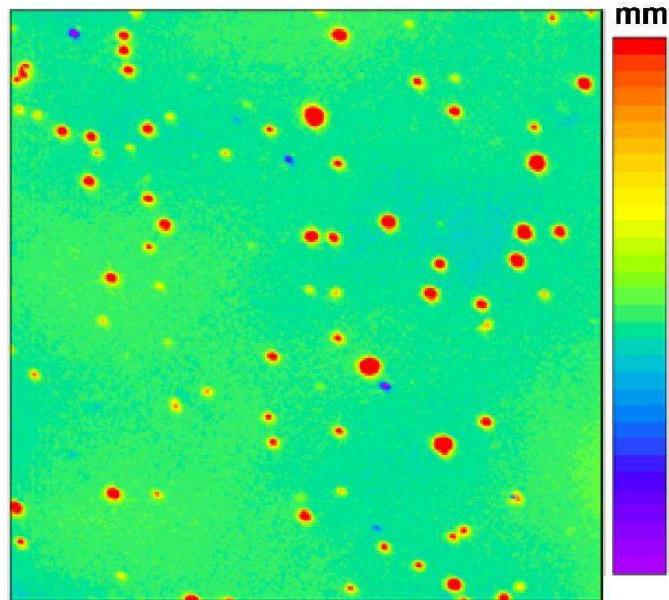
Results

mosi20x_01.mmd RS: 23670 mm
 Mo/Si RCa: -53430 mm
 Op: Mitte RCb: 9689 mm
 Area: 235.2 x 235.2 μm^2
 2009-03-20 Smooth Phase 0.356



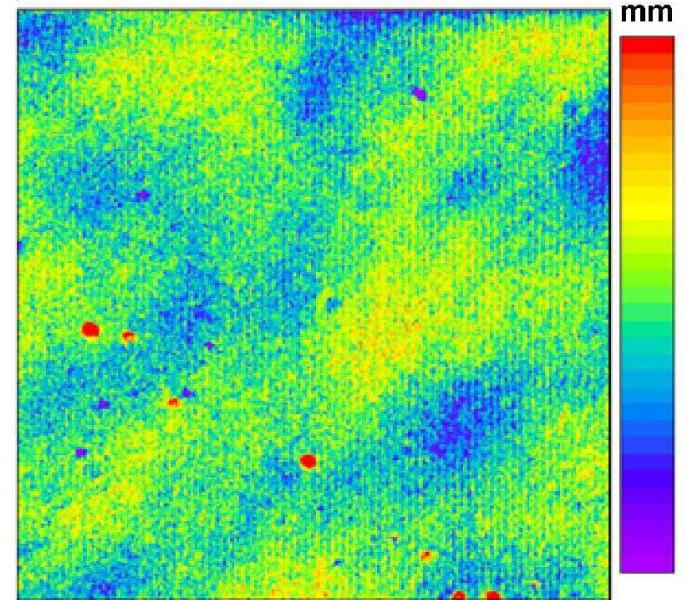
Sq: 0.118 mm 480 x 480 -0.354 mm
 Sa: 0.0772 mm 1/2" CCD
 St: 7.693 mm 1.0x Body
 No Relay
 Points: 230400 520 nm Phase
 Quartic 20x

pdb4c20x_02.mmd RS: -50660 mm
 Pd/B4C RCa: -313200 mm
 Op: Mitte RCb: -27560 mm
 Area: 235.2 x 235.2 μm^2
 2009-03-20 Smooth Phase 2.457



Sq: 0.819 mm 480 x 480 -2.457 mm
 Sa: 0.202 mm 1/2" CCD
 St: 30.46 mm 1.0x Body
 No Relay
 Points: 230400 520 nm Phase
 Quartic 20x

wsi20x_01.mmd RS: 54600 mm
 W/Si RCa: 905800 mm
 Op: Mitte RCb: 28150 mm
 Area: 235.2 x 235.2 μm^2
 2009-03-20 Smooth Phase 0.218



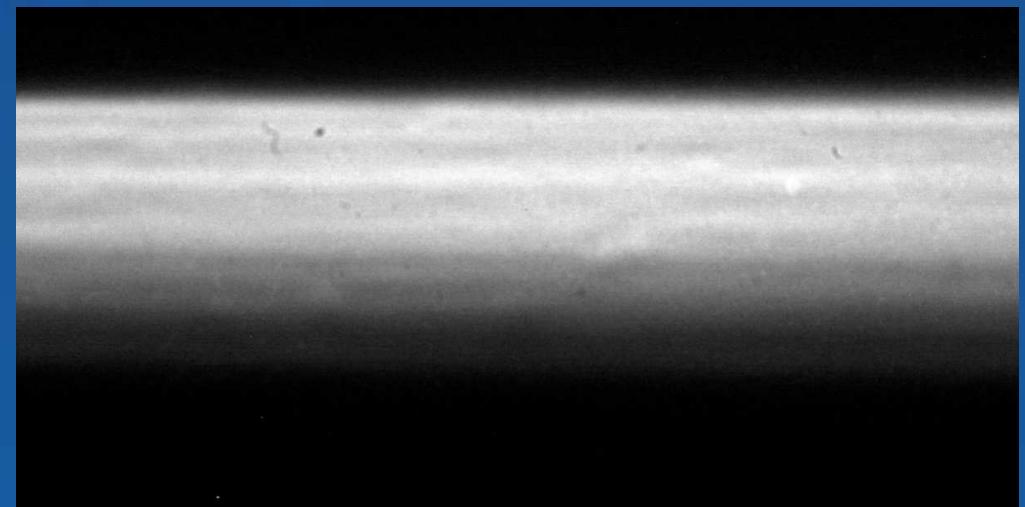
Sq: 0.0722 mm 480 x 480 -0.215 mm
 Sa: 0.0528 mm 1/2" CCD
 St: 2.879 mm 1.0x Body
 No Relay
 Points: 230400 520 nm Phase
 Quartic 20x

substrates: all similar high level of surface quality;
 multilayers: strongly varying interlayer and surface roughness

Pd/B₄C



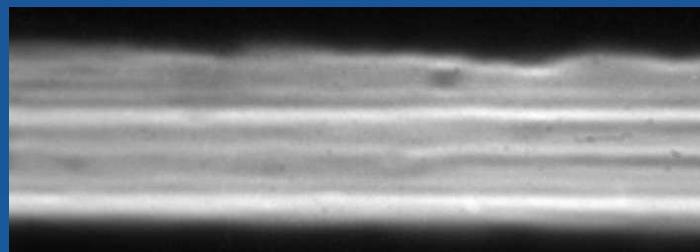
N = 30
d = 3.982 nm



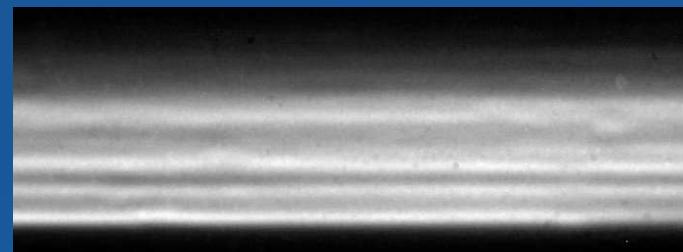
N = 60
d = 4.002 nm

E = 18 keV

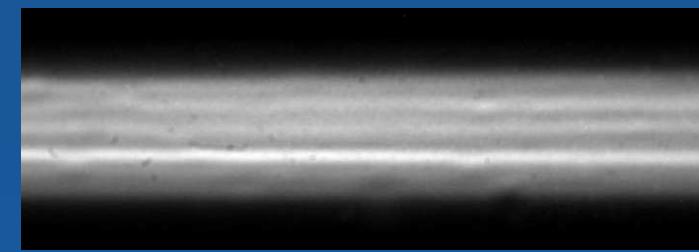
Mo/Si

 $d = 2.478 \text{ nm}$

(N = 220)

 $d = 3.975 \text{ nm}$

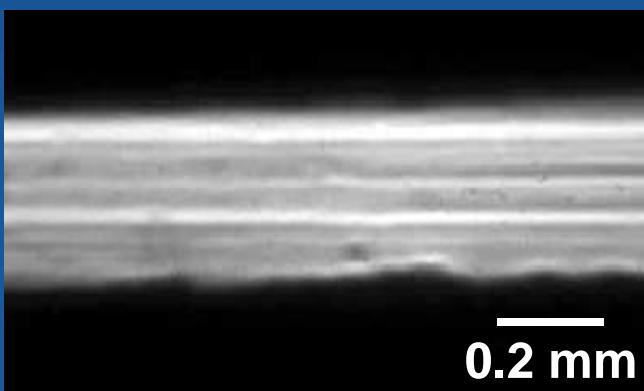
(N = 80)

 $d = 5.492 \text{ nm}$

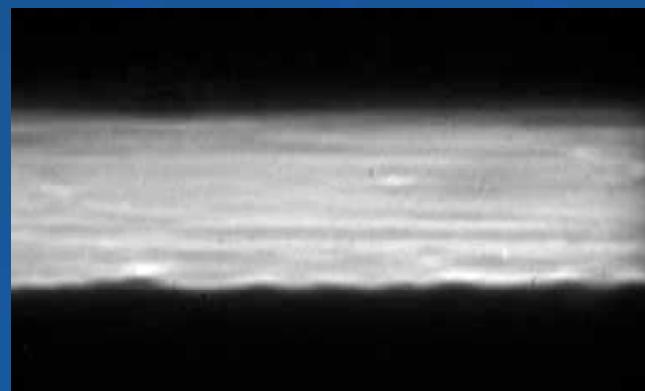
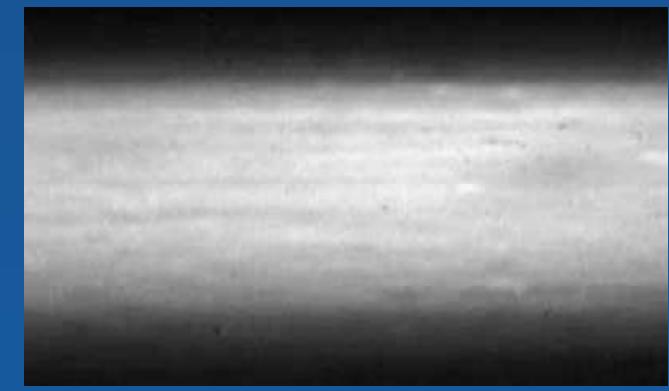
(N = 50)

 $E = 18 \text{ keV}$

Mo/Si



W/Si

Pd/B₄C $d = 2.478 \text{ nm}$

(N = 220)

 $d = 2.528 \text{ nm}$

(N = 120)

 $d = 2.468 \text{ nm}$

(N = 220)

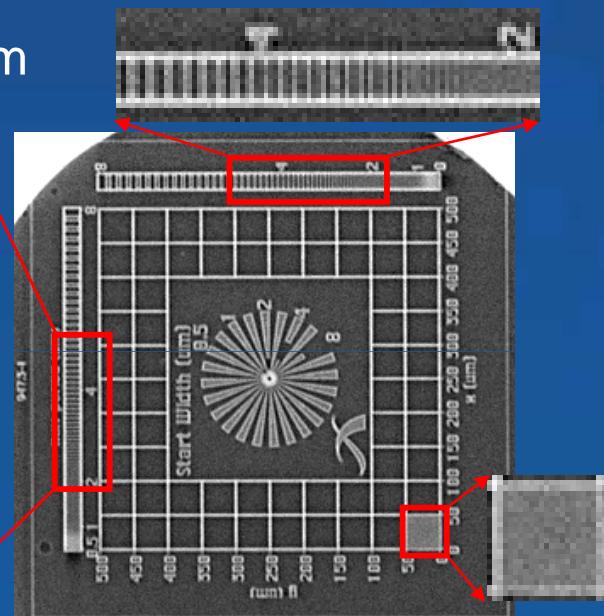
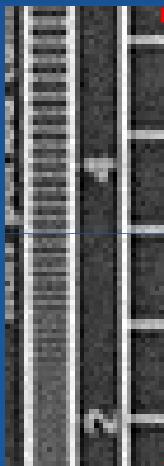
 $E = 18 \text{ keV}$

Serial number	Materials	N	d (nm)	R_8^{exp}	R_8^{calc}	R_{18}^{calc}
1531	W/Si	120	2.528	-†	76%	78%
1574	Mo/Si	220	2.478	>45% †	77%	93%
1601	Mo/Si	80	3.975	70%	77%	93%
1609	Mo/Si	50	5.492	75%	76%	93%
1680	Pd/B ₄ C	220	2.468	>50% †	76%	93%
1681	Pd/B ₄ C	60	4.002	70%	76%	93%
1685	Pd/B ₄ C	30	3.982	61%	70%	86%

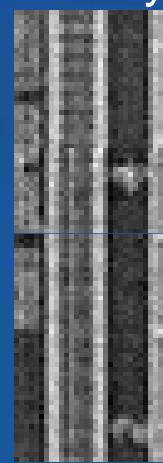
similar values

Full-field Micro-Imaging

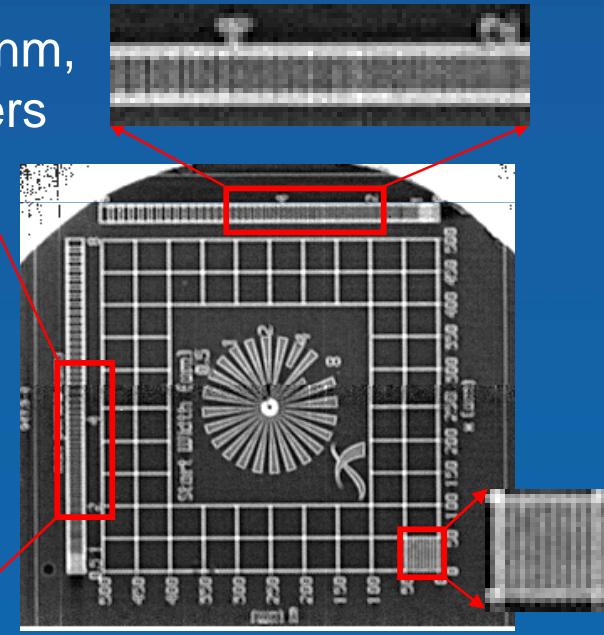
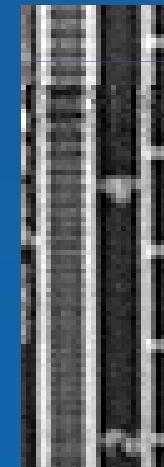
white beam



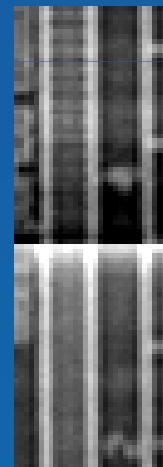
W/Si, 2.5 nm,
120 bi-layers



Pd/B₄C, 2.5 nm,
220 bi-layers

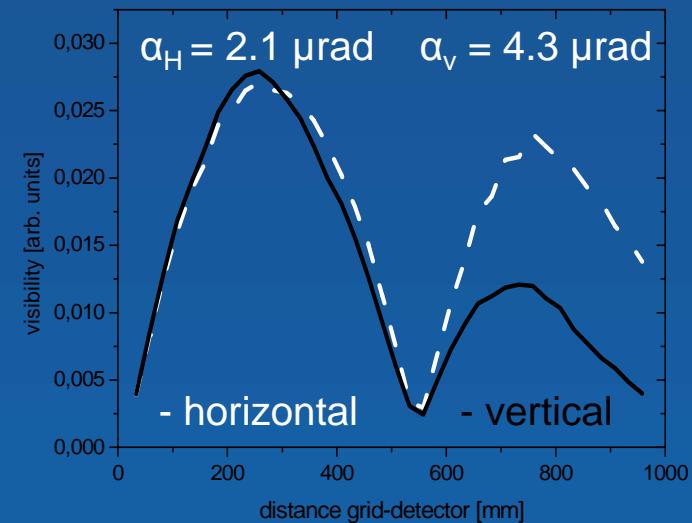
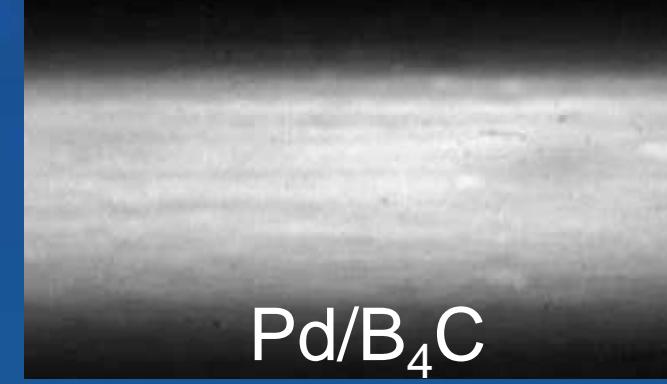
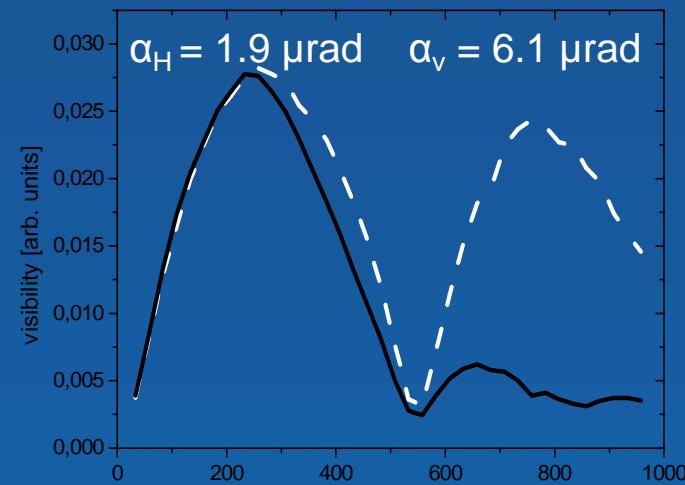
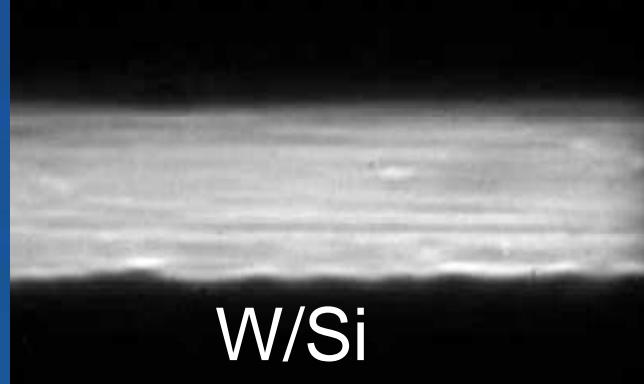
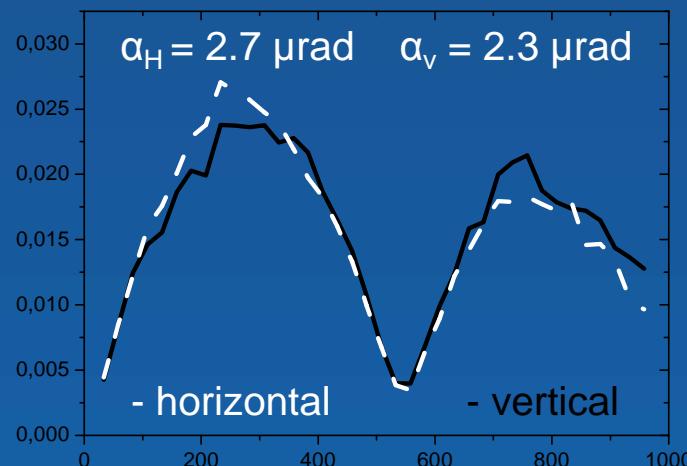


Mo/Si, 2.5 nm,
220 bi-layers

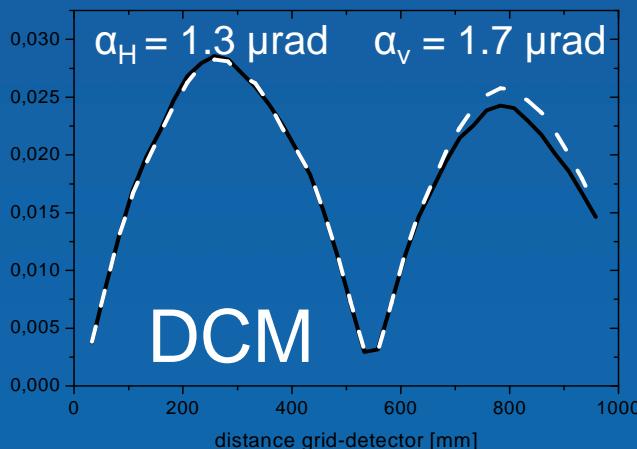


E =
18 keV

Coherence Preservation

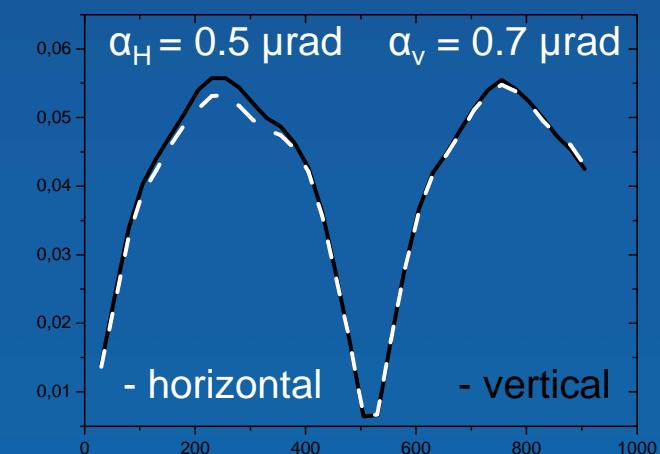
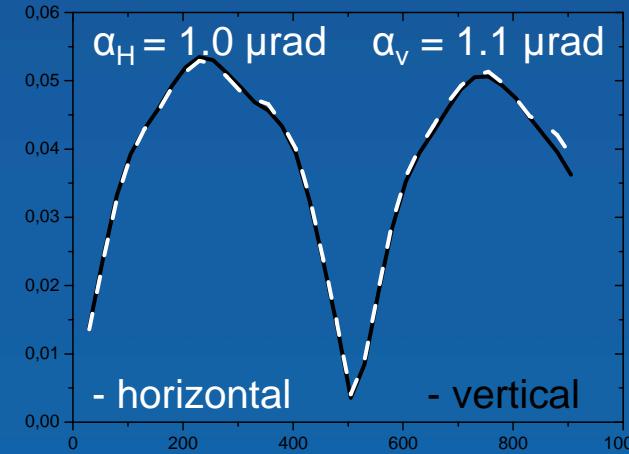
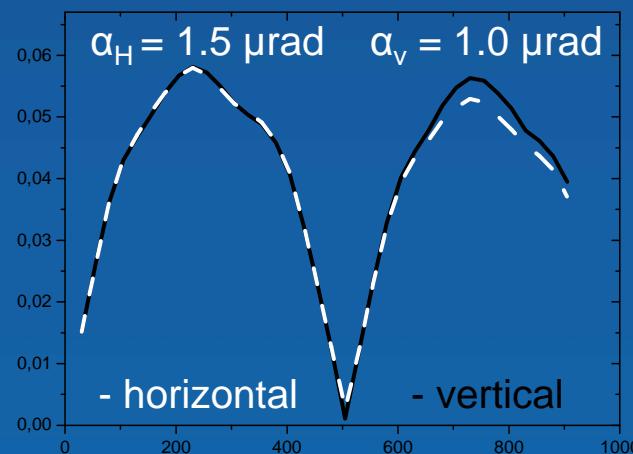
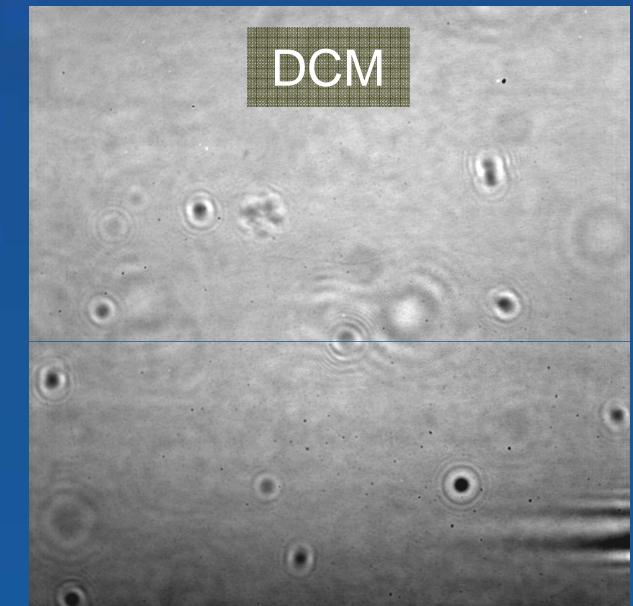
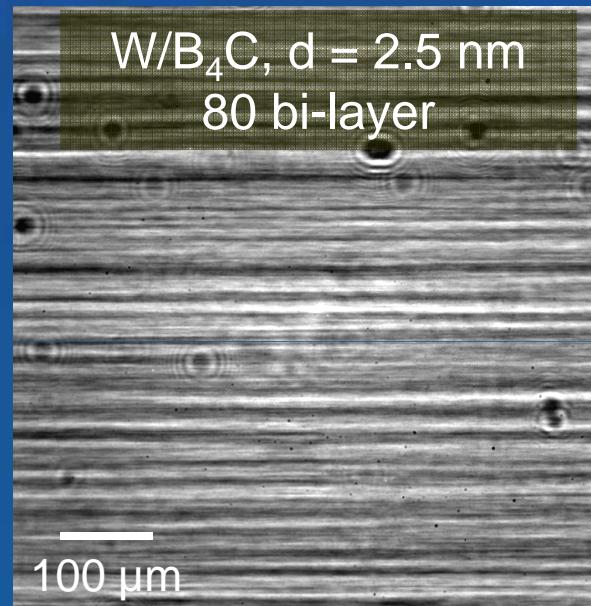
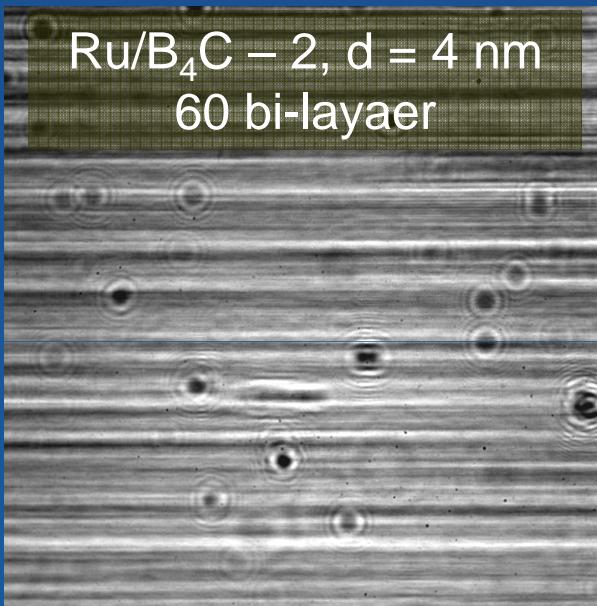


- similar substrate roughness (F. Siewert - BESSY), 1" dia.
- similar surface layer as well as interlayer roughness (XRR)

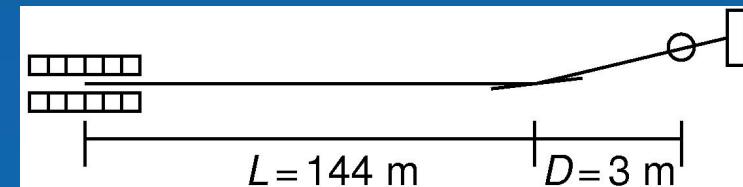


- similar spatial resolution reachable
- different coherence properties
- different stripe patterns

Discussion

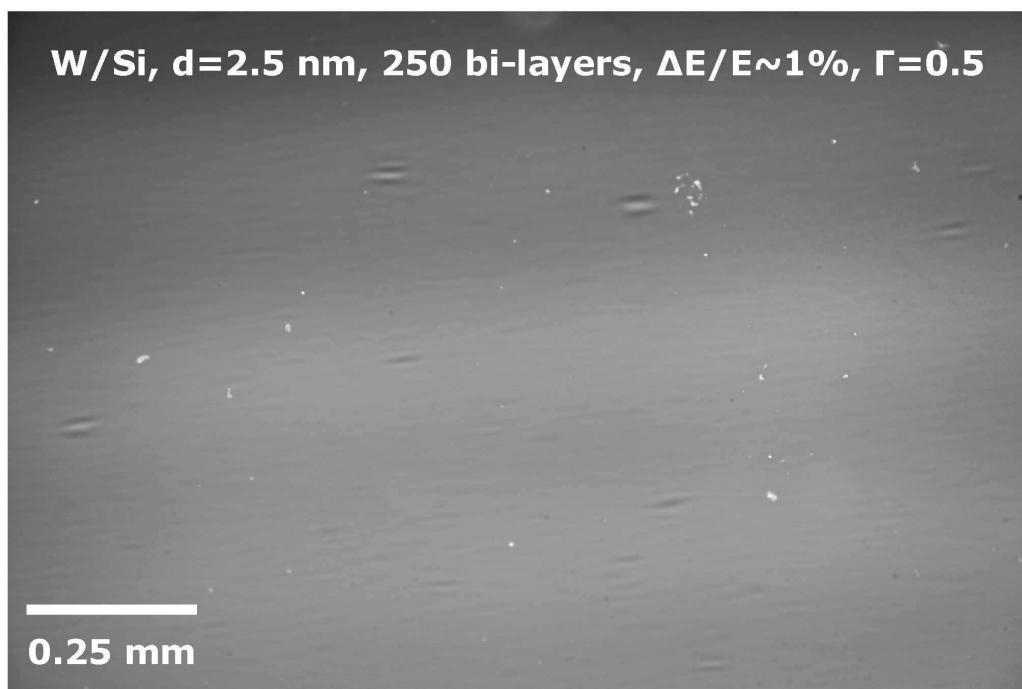


E = 18 keV



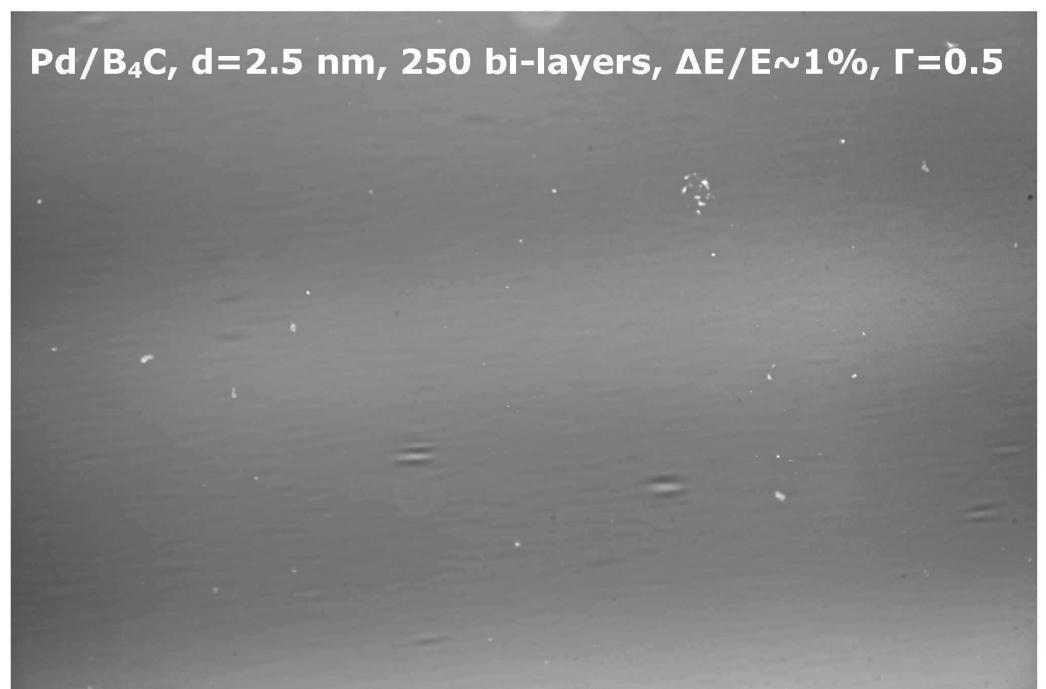
0.35 μm pixel size

W/Si, d=2.5 nm, 250 bi-layers, $\Delta E/E \sim 1\%$, $\Gamma = 0.5$



0.25 mm

Pd/B₄C, d=2.5 nm, 250 bi-layers, $\Delta E/E \sim 1\%$, $\Gamma = 0.5$



$E = 18$ keV, indirect high resolution detector with 0.36 μm pixel size (resolving power < 2 μm), 500 $\mu\text{m} \times 150$ μm source

Thanks for your attention!

Rack, Weitkamp et al., J Synchrotron Radiation
vol. 17, no. 4 (2010)
DOI [10.1107/S0909049510011623](https://doi.org/10.1107/S0909049510011623)

Rack, Weitkamp et al., NIMA Special Issue SRI2010 (submitted)

To support the Upgrade >>> www.esrf.eu/Upgrade

